SWITCHING VOLTAGE REGULATORS

SLVS009D - JUNE 1976 - REVISED JULY 1999

- High Efficiency . . . 60% or Greater
- Output Current . . . 500 mA
- Input Current Limit Protection
- **TTL-Compatible Inhibit**
- Adjustable Output Voltage
- Input Regulation . . . 0.2% Typ
- Output Regulation . . . 0.4% Typ
- Soft Start-Up Capability

description

The TL497A incorporates all the active functions required in the construction of switching voltage regulators. It can also be used as the control

(TOP VIEW) COMP INPUT V_{CC} **INHIBIT** 13 CUR LIM SENS FREQ CONTROL [BASE DRIVET SUBSTRATE 11 BASE[†] **GND** 10 COL OUT CATHODE 9∏ NC ANODE **EMIT OUT** 8

D, N, OR PW PACKAGE

NC - No internal connection

† BASE (11) and BASE DRIVE (12) are used for device testing only. They normally are not used in circuit applications of the

element to drive external components for high-power-output applications. The TL497A was designed for ease of use in step-up, step-down, or voltage-inversion applications requiring high efficiency.

The TL497A is a fixed-on-time variable-frequency switching-voltage-regulator control circuit. The switch-on time is programmed by a single external capacitor connected between FREQ CONTROL and GND. This capacitor, C_T, is charged by an internal constant-current generator to a predetermined threshold. The charging current and the threshold vary proportionally with V_{CC}. Thus, the switch-on time remains constant over the specified range of input voltage (4.5 V to 12 V). Typical on times for various values of C_T are as follows:

TIMING CAPACITOR, C _T (pF)	200	250	350	400	500	750	1000	1500	2000
ON TIME (μs)	19	22	26	32	44	56	80	120	180

The output voltage is controlled by an external resistor ladder network (R1 and R2 in Figures 1, 2, and 3) that provides a feedback voltage to the comparator input. This feedback voltage is compared to the reference voltage of 1.2 V (relative to SUBSTRATE) by the high-gain comparator. When the output voltage decays below the value required to maintain 1.2 V at the comparator input, the comparator enables the oscillator circuit, which charges and discharges C_T as described above. The internal pass transistor is driven on during the charging of C_T. The internal transistor can be used directly for switching currents up to 500 mA. Its collector and emitter are uncommitted, and it is current driven to allow operation from the positive supply voltage or ground. An internal Schottky diode matched to the current characteristics of the internal transistor also is available for blocking or commutating purposes. The TL497A also has on-chip current-limit circuitry that senses the peak currents in the switching regulator and protects the inductor against saturation and the pass transistor against overstress. The current limit is adjustable and is programmed by a single sense resistor, RCI, connected between V_{CC} and CUR LIM SENS. The current-limit circuitry is activated when 0.7 V is developed across R_{CL} . External gating is provided by the INHIBIT input. When the INHIBIT input is high, the output is turned off.

Simplicity of design is a primary feature of the TL497A. With only six external components (three resistors, two capacitors, and one inductor), the TL497A operates in numerous voltage-conversion applications (step-up, step-down, invert) with as much as 85% of the source power delivered to the load. The TL497A replaces the TL497 in all applications.

The TL497AC is characterized for operation from 0°C to 70°C. The TL497AI is characterized for operation from -40°C to 85°C.



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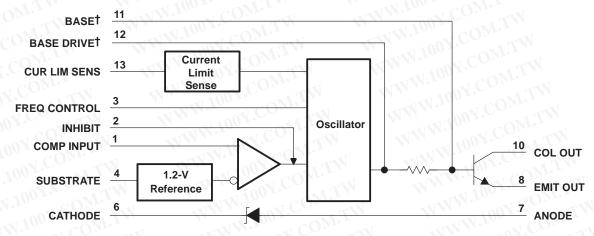


AVAILABLE OPTIONS

TIWW.	PA	CKAGED DEVIC	ES V.CO	TVOLUB
TA 1.10	SMALL-OUTLINE (D)	PLASTIC DIP (N)	SHRINK SMALL-OUTLINE (PW)	CHIP FORM (Y)
0°C to 70°C	TL497ACD	TL497ACN	TL497ACPW	TL497AY
-40°C to 85°C	TL497AID	TL497AIN	4007.0	TW

The D and PW packages are only taped and reeled. Add the suffix R to the device type (e.g., TL497ACPWR). Chip forms are tested at 25°C.

functional block diagram



† BASE and BASE DRIVE are used for device testing only. They normally are not used in circuit applications of the device. WWW.100Y.COM.TW

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)		15 V
Output voltage, VO		
Input voltage, V _I (COMP INPUT)	-Μ.Υ	5 V
Input voltage, V _I (INHIBIT)	······································	5 V
Diode reverse voltage	\$1.YY	
Power switch current	vv.N	750 mA
Diode forward current		750 mA
Package thermal impedance, θ_{JA} (see Notes 2 and 3): D package	86°C/W
OM. TW WWW.100Y.COM.TW	N package	101°C/W
	PW package	113°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 6	0 seconds	260°C
Storage temperature range, T _{stq}		. −65°C to 150°C

[†]Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values except diode voltages are with respect to network ground terminal.

- 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
- 3. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions

MAN COMPAN	MANN. COL. TOW	WWW	MIN	MAX	UNIT
Supply voltage, VCC	L. M. Inn. COM.	T.WW.I	4.5	12	v V
High-level input voltage, VIH	INHIBIT pin		2.5	M_{II}	V
Low-level input voltage, V _{IL}	INHIBIT pin			0.8	V
M.Ing. COM.	Step-up configuration (see Figure 1)	WW.	V _I + 2	30	TXX.
Output voltage	Step-down configuration (see Figure 2)		V		
	Inverting regulator (see Figure 3)	TW WW	-V _{ref}	-25	
Power switch current		11.5	500	mA	
Diode forward current			MIN.Tu	500	mA
TL497AC		TL497AC	0	70	°C
Operating free-air temperature range	le, IA	TL497AI	-40	85	



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electrical characteristics over recommended operating conditions, V_{CC} = 6 V (unless otherwise noted)

ONL.	TEOTO	ONDITIONS	_ ****	11.5	TL497AC	$O_{M_{\pi}}$	rW.	TL497AI		
PARAMETER	1 10 IEST C	ONDITIONS	T _A †	MIN	TYP [‡]	MAX	MIN	TYP [‡]	MAX	UNIT
High-level input current, INHIBIT	V _{I(I)} = 5 V	-ow.TW	Full range	TXN	0.8	1.5	T. I.	0.8	1.5	mA
Low-level input current, INHIBIT	V _{I(I)} = 0 V	.Co. TW	Full range		5	10	TY	5	20	μΑ
Comparator reference voltage	V _I = 4.5 V t	0 6 V	Full range	1.08	1.2	1.32	1.14	1.2	1.26	V
Comparator input bias current	V _I = 6 V	COM	Full range	-111	40	100)Mr.	40	100	μΑ
	V ~ 1510	I _O = 100 mA	25°C	Al.	0.13	0.2	M	0.13	0.2	
Switch on-state voltage	V _I = 4.5 V	I _O = 500 mA	Full range		-11	0.85	~1/	IM	1	V
60	VAEV		25°C	W	10	50	Co_{Σ}	10	50	
Switch off-state current	$V_1 = 4.5 V,$	VO = 30 V	Full range		WW	200		1.	500	μΑ
Sense voltage, CUR LIM SENS	V _I = 6 V	11007.	25°C	0.45	N 1 1	1.101	0.45	Mir	_ 1	V
ON CONTRACTOR	I _O = 10 mA	100X.C	Full range		0.75	0.85	Y.	0.75	0.95	
Diode forward voltage	I _O = 100 m.	A C	Full range		0.9	1	NY.C	0.9	1.1	V
	$I_0 = 500 \text{ m}.$	A VI	Full range		1.33	1.55		1.33	1.75	
Disable 4.000	ΙΟ = 500 μΑ	1 100 1.	Full range		7.	-TIN	30	COM		V
Diode reverse voltage	$I_0 = 200 \mu$	M. 100X	Full range	30		7	1007		I.I.M	V
W.W. Tar Com		WW.	25°C	W	11 <	14	400	1. 11	14	N A
On-state supply current			Full range			15	N'ra.	ov CC	16	mA
Off and a second of the second	N.	W 1 10	25°C	11.4	6	9	W.10	6	0//9	. Tac Ta
Off-state supply current			Full range	WIT		10	- 1	001.	-11	mA

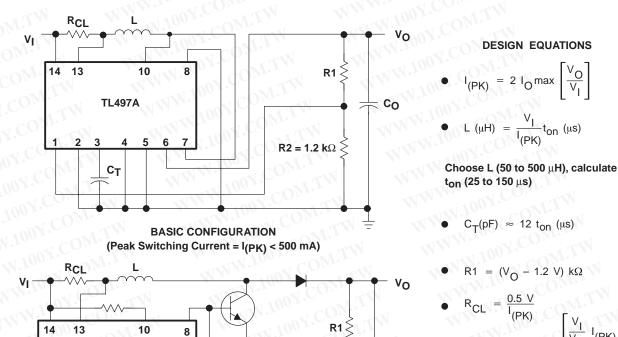
[†] Full range is 0°C to 70°C for the TL497AC and -40°C to 85°C for the TL497AI.

electrical characteristics over recommended operating conditions, V_{CC} = 6 V, T_A = 25°C (unless otherwise noted)

DADAMETED	TEST CONDITIONS	TL497AY	
PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
High-level input current, INHIBIT	V _{I(I)} = 5 V	0.8	mA
Low-level input current, INHIBIT	V _{I(I)} = 0 V	5	μA
Comparator reference voltage	V _I = 4.5 V to 6 V	1.2	V
Comparator input bias current	V _I = 6 V	40	μА
Switch on-state voltage	V _I = 4.5 V, I _O = 100 mA	0.13	V
Switch off-state current	$V_{I} = 4.5 \text{ V}, \qquad V_{O} = 30 \text{ V}$	10	μА
W 1001. ON.TW	I _O = 10 mA	0.75	100
liode forward voltage	I _O = 100 mA	0.9	1 (V)
M.M. TON. COM.	I _O = 500 mA	1.33	400
On-state supply current	TIMAN TOO COM.	11	mA
Off-state supply current	W. 100 . CON	6	mA



[‡] All typical values are at $T_A = 25$ °C.



EXTENDED POWER CONFIGURATION (using external transistor)

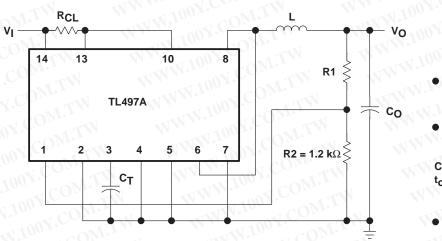
TL497A

CT

3 4

Figure 1. Positive Regulator, Step-Up Configurations

 $R2 = 1.2 k\Omega$



BASIC CONFIGURATION (Peak Switching Current = I_(PK) < 500 mA)

DESIGN EQUATIONS

- \bullet $I_{(PK)} = 2 I_{O} \max$
- L (μ H) = $\frac{V_I V_O}{I_{(PK)}} t_{ON}(\mu s)$

Choose L (50 to 500 μ H), calculate t_{on} (10 to 150 μ s)

- $C_T(pF) \approx 12 t_{on}(\mu s)$
- R1 = $(V_O 1.2 \text{ V}) \text{ k}\Omega$
- C_{O} (μF) $\approx t_{ON}(\mu s) \frac{\left[\frac{V_{I} V_{O}}{V_{O}}\right]^{I}(PK)^{I} + I_{O}}{V_{ripple}}$

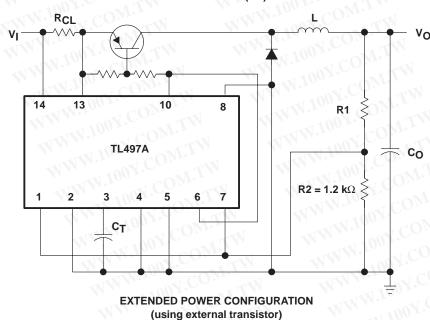
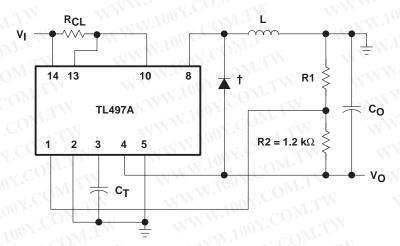
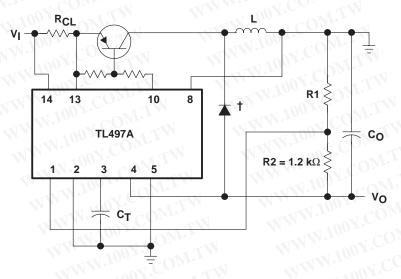


Figure 2. Positive Regulator, Step-Down Configurations



BASIC CONFIGURATION (Peak Switching Current = I_(PK) < 500 mA)



EXTENDED POWER CONFIGURATION (using external transistor)

† Use external catch diode, e.g., 1N4001, when building an inverting supply with the TL497A.

Figure 3. Inverting Applications

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DESIGN EQUATIONS $I_{(PK)} = 2 I_{O} \max \left[1 + \frac{|V_{O}|}{V} \right]$

• L (
$$\mu$$
H) = $\frac{V_I}{I_{(PK)}}t_{ON}(\mu s)$

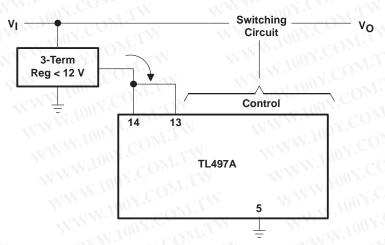
Choose L (50 to 500 $\mu\text{H}),$ calculate $t_{\mbox{on}}$ (10 to 150 $\mu\text{s})$

•
$$C_T(pF) \approx 12 t_{on}(\mu s)$$

• R1 =
$$(|V_{\Omega}| - 1.2 \text{ V}) \text{ k}\Omega$$

$$R_{CL} = \frac{0.5 \text{ V}}{I_{(PK)}}$$

$$C_{O} (\mu F) \approx t_{ON}(\mu s) \frac{\left[\frac{V_{I}}{|V_{O}|} I_{(PK)} + I_{O}\right]}{V_{ripple} (PK)}$$



EXTENDED INPUT CONFIGURATION WITHOUT CURRENT LIMIT

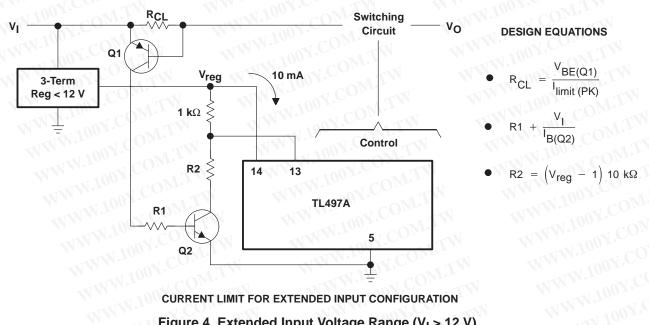


Figure 4. Extended Input Voltage Range (V_I > 12 V)

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